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## November 2013

# FQD1N60C / FQU1N60C N-Channel QFET<sup>®</sup> MOSFET 600 V, 1.0 A, 11.5 Ω

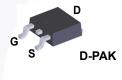
## Features

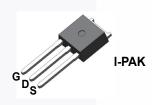
- 1 A, 600 V,  ${\rm R}_{\rm DS(on)}$  = 11.5  $\Omega$  (Max.) @ V\_{\rm GS} = 10 V,  ${\rm I}_{\rm D}$  = 0.5 A
- Low Gate Charge (Typ. 4.8 nC)
- Low Crss (Typ. 3.5 pF)
- 100% Avalanche Tested
- RoHS Compliant

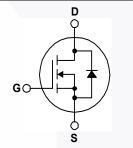


# Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power factor correction (PFC), and electronic lamp ballasts.







# Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

Symbol	Parameter		FQD1N60CTM / FQU1N60CTU	Unit
V <sub>DSS</sub>	Drain-Source Voltage		600	V
I <sub>D</sub>	Drain Current - Continuous ( $T_C = 25^{\circ}C$ )		1	А
	- Continuous (T <sub>C</sub> = 100°C)		0.6	А
I <sub>DM</sub>	Drain Current - Pulsed	(Note 1)	4	А
V <sub>GSS</sub>	Gate-Source Voltage		± 30	V
E <sub>AS</sub>	Single Pulsed Avalanche Energy (Note		33	mJ
I <sub>AR</sub>	Avalanche Current	(Note 1)	1	А
E <sub>AR</sub>	Repetitive Avalanche Energy	(Note 1)	2.8	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)		4.5	V/ns
	Power Dissipation (T <sub>A</sub> = 25°C)*		2.5	W
P <sub>D</sub>	Power Dissipation (T <sub>C</sub> = 25°C)		28	W
	- Derate above 25°C		0.22	W/°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range		-55 to +150	°C
TL	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds		300	°C

# **Thermal Characteristics**

Symbol	Parameter	FQD1N60CTM / FQU1N60CTU	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction-to-Case, Max. 4.53		
D	Thermal Resistance, Junction-to-Ambient (minimum pad of 2 oz copper), Max.	110	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction-to-Ambient (* 1 in <sup>2</sup> pad of 2 oz copper), Max.	50	

Device Marking		Device	Package	Reel Size	Таре	Width	Qua	antity
FQD1N60C		FQD1N60CTM	D-PAK	330mm	16mm		2500 units	
FQU1N60C FQU1N60CTU		I-PAK	Tube	N/A		70 units		
	cal Char	acteristics T <sub>C</sub> = 25°C	cunless otherwise	noted.				1
Symbol		Parameter	Test Conditions		Min	Тур	Max	Unit
Off Cha	aracteristi	cs						
BV <sub>DSS</sub>	Drain-Source	ce Breakdown Voltage	$V_{GS} = 0 V, I_D = 2$	50 μΑ	600			V
ΔBV <sub>DSS</sub> / ΔT <sub>J</sub>	Breakdown Coefficient	Voltage Temperature	I <sub>D</sub> = 250 μA, Referenced to 25°C			0.6		V/°C
1	Zero Gate Voltage Drain Current		V <sub>DS</sub> = 600 V, V <sub>GS</sub> = 0 V				1	μA
IDSS			V <sub>DS</sub> = 480 V, T <sub>C</sub> = 125°C				10	μA
I <sub>GSSF</sub>	Gate-Body	Leakage Current, Forward	$V_{GS}$ = 30 V, $V_{DS}$	= 0 V			100	nA
I <sub>GSSR</sub>	Gate-Body	Leakage Current, Reverse	$V_{GS}$ = -30 V, $V_{DS}$	s = 0 V			-100	nA
On Cha	racteristic	cs						
V <sub>GS(th)</sub>	Gate Thres	hold Voltage	$V_{DS} = V_{GS}, I_D = 2$	250 μA	2.0		4.0	V
R <sub>DS(on)</sub>	Static Drain-Source On-Resistance		$V_{GS}$ = 10 V, I <sub>D</sub> = 0.5 A			2.8	3.4	Ω
9 <sub>FS</sub>	Forward Transconductance		V <sub>DS</sub> = 40 V, I <sub>D</sub> = 0.5 A			3.5		S
Dynami	ic Charact	teristics						
C <sub>iss</sub>	Input Capa	citance	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1.0 MHz			130	170	pF
C <sub>oss</sub>	Output Cap	pacitance				19	25	pF
C <sub>rss</sub>	Reverse Tr	ansfer Capacitance				3.5	4.5	pF
Switchi	ing Chara	cteristics						
t <sub>d(on)</sub>	Turn-On De	elay Time	$V_{DD}$ = 300 V, I <sub>D</sub> = 1.1 A, R <sub>G</sub> = 25 Ω			7	24	ns
t <sub>r</sub>	Turn-On Ri	se Time				21	52	ns
t <sub>d(off)</sub>	Turn-Off De	elay Time				13	36	ns
t <sub>f</sub>	Turn-Off Fa	III Time		(Note 4)	/	27	64	ns
Qg	Total Gate	Charge	$V_{DS} = 480 \text{ V}, \text{ I}_{D} = 1.1 \text{ A},$ $V_{GS} = 10 \text{ V}$			4.8	6.2	nC
Q <sub>gs</sub>	Gate-Sourc	e Charge				0.7		nC
Q <sub>gd</sub>	Gate-Drain	Charge		(Note 4)		2.7		nC
Drain-S	ource Dic	ode Characteristics a	nd Maximum F	Ratings				
I <sub>S</sub>		Continuous Drain-Source Dic					1	Α
I <sub>SM</sub>		Pulsed Drain-Source Diode F					4	А
V <sub>SD</sub>	Drain-Source	ce Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 0$	).5 A			1.4	V
						100		<u> </u>

t<sub>rr</sub>

1. Repetitive Rating : Pulse width limited by maximum junction temperature.

2. L = 59 mH, I\_{AS} = ~ 1.1 A, V\_{DD} = 50 V, R\_G = 25  $\Omega,$  starting ~ T\_J = 25°C.

**Reverse Recovery Time** 

Reverse Recovery Charge

3. I\_{SD}  $\leq$  1.1 A, di/dt  $\leq$  200 A/µs, V\_{DD}  $\leq$  BV\_{DSS,} starting ~ T\_{J} = 25°C.

4. Essentially independent of operating temperature.

 $V_{GS} = 0 V, I_{S} = 1.1 A,$ 

 $dI_F / dt = 100 A/\mu s$ 

ns

μC

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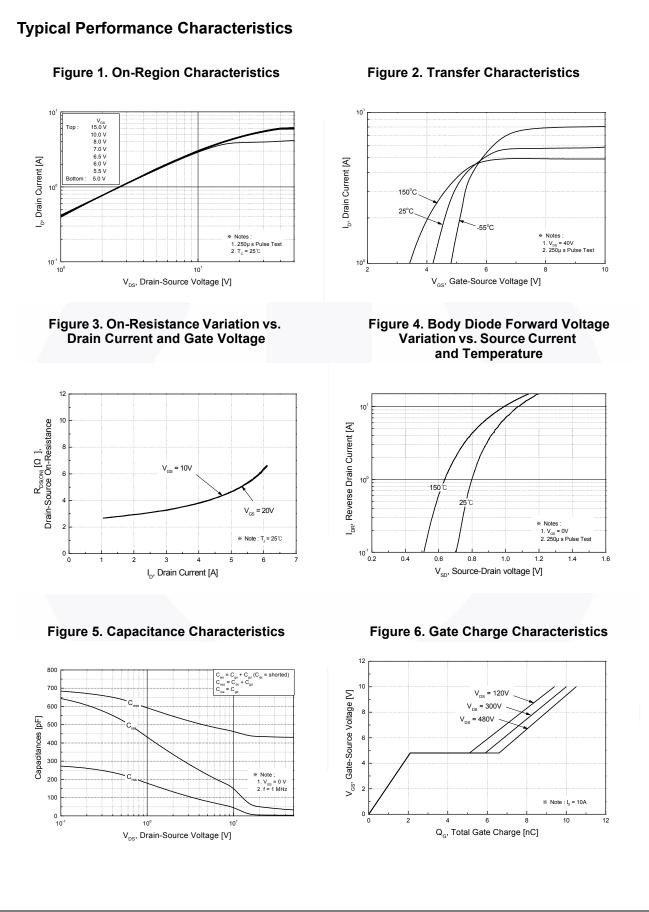
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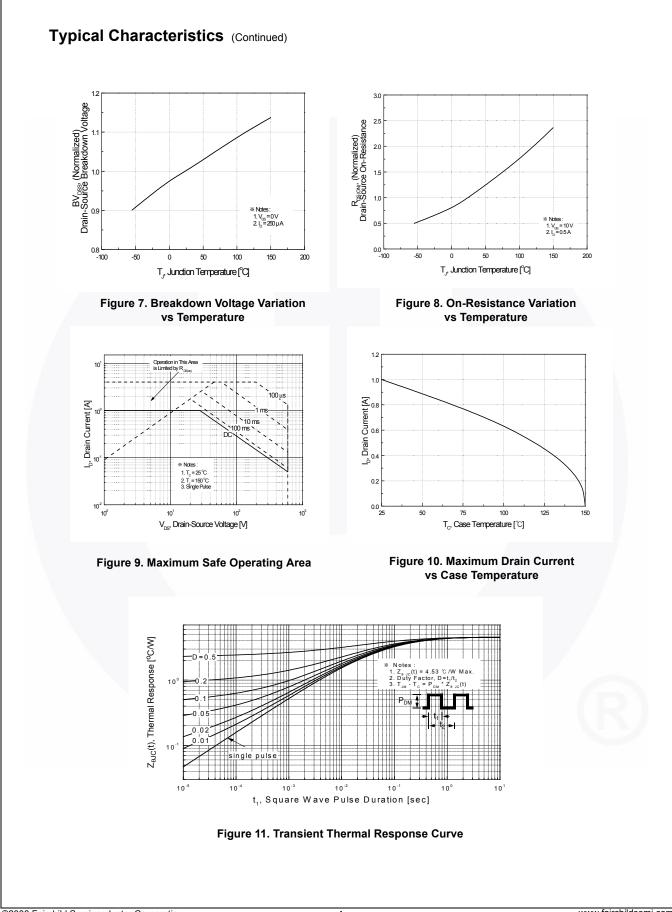
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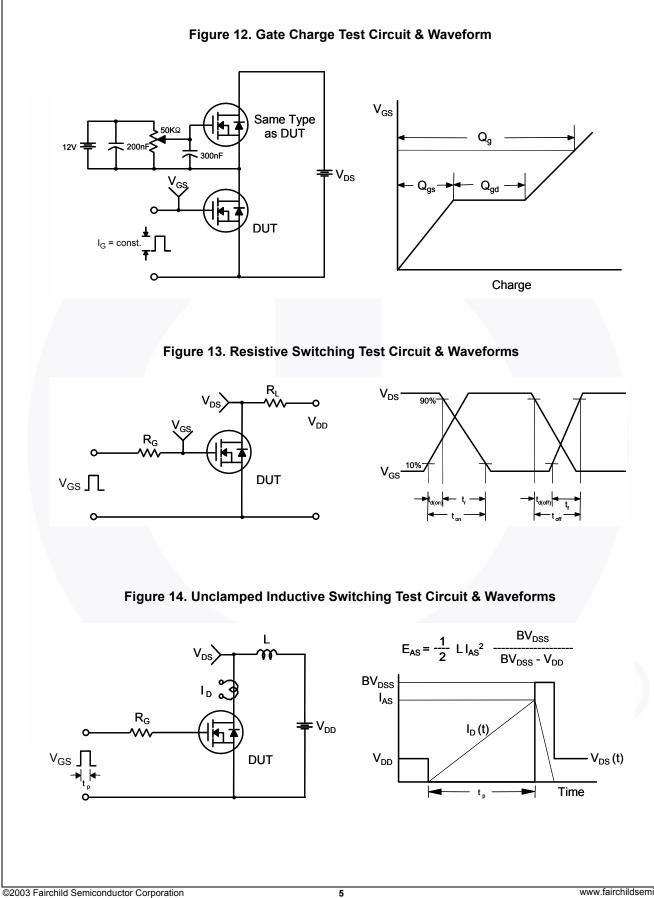
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FQD1N60C / FQU1N60C — N-Channel QFET<sup>®</sup> MOSFET



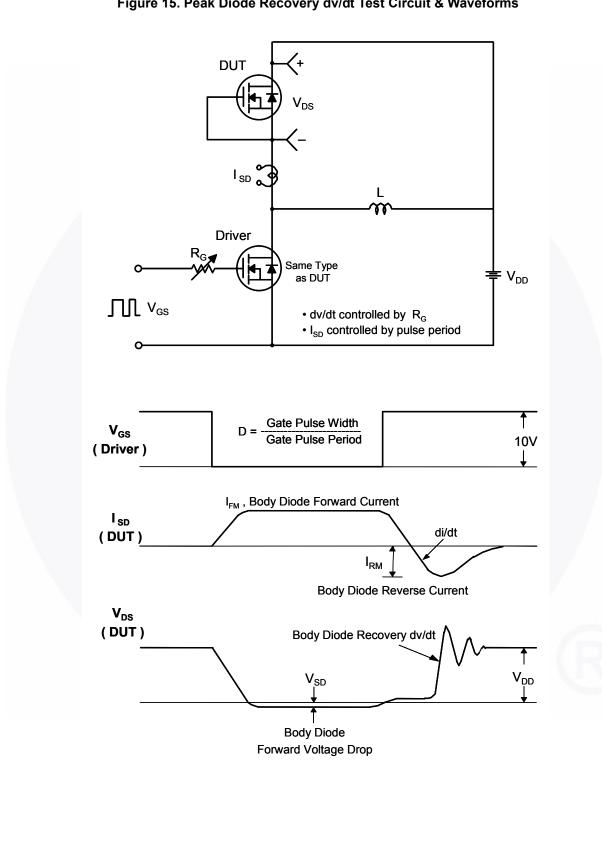
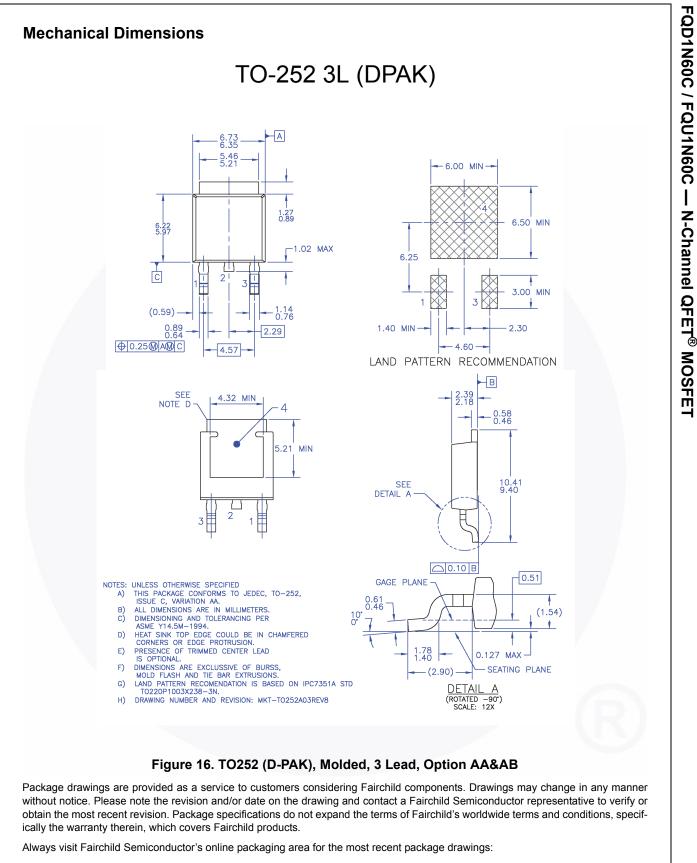
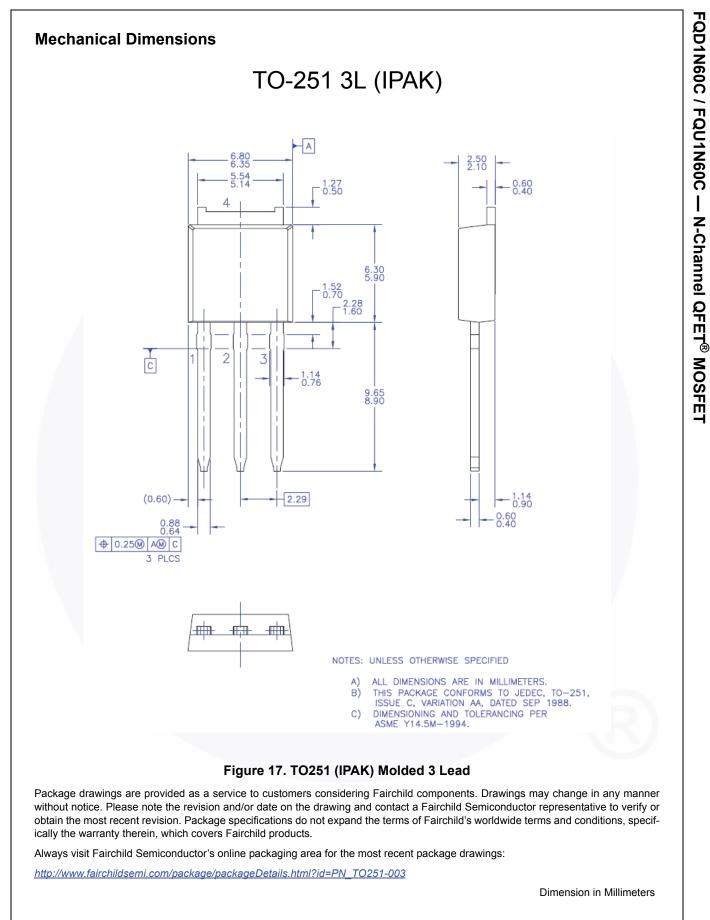


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms



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**Dimension in Millimeters** 





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